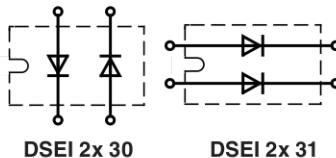


Fast Recovery Epitaxial Diode (FRED)

$I_{FAVM} = 2 \times 30 \text{ A}$
 $V_{RRM} = 400/600 \text{ V}$
 $t_{rr} = 35 \text{ ns}$

V_{RSM}	V_{RRM}	Type
V	V	
440	400	DSEI 2x 30-04C
640	600	DSEI 2x 30-06C
		DSEI 2x 31-04C
		DSEI 2x 31-06C



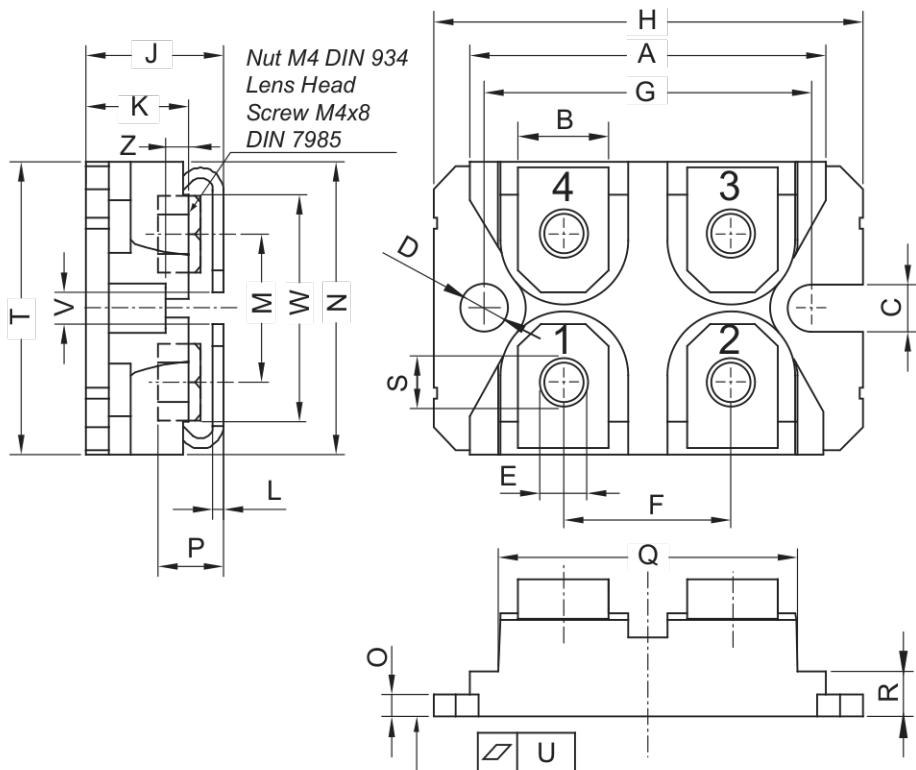
miniBLOC, SOT-227 B



Symbol	Test Conditions	Maximum Ratings (per diode)		
I_{FRMS}	$T_{VJ} = T_{VJM}$	70	A	
I_{FAVM} ①	$T_c = 85^\circ\text{C}$; rectangular, $d = 0.5$	30	A	
I_{FRM}	$t_p < 10 \mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	375	A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	300	A	
		320	A	
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	260	A	
		280	A	
I^2t	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	450	A^2s	
		420	A^2s	
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	340	A^2s	
		320	A^2s	
T_{VJ}		-40...+150	$^\circ\text{C}$	
T_{VJM}		150	$^\circ\text{C}$	
T_{stg}		-40...+150	$^\circ\text{C}$	
P_{tot}	$T_c = 25^\circ\text{C}$	100	W	
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	2500	V~	
M_d	Mounting torque Terminal connection torque (M4)	1.5/13	Nm/lb.in.	
		1.5/13	Nm/lb.in.	
Weight		30	g	
Symbol	Test Conditions	Characteristic Values (per diode)		
		typ.	max.	
I_R	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$		100	μA
			50	μA
			7	mA
V_F	$I_F = 30 \text{ A}$; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$		1.4	V
			1.6	V
V_{TO}	For power-loss calculations only		1.01	V
r_T	$T_{VJ} = T_{VJM}$		7.1	$\text{m}\Omega$
R_{thJC}		0.05	1.25	K/W
R_{thCK}				K/W
t_{rr}	$I_F = 1 \text{ A}$; $-\text{di}/\text{dt} = 100 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	35	50	ns
I_{RM}	$V_R = 350 \text{ V}$; $I_F = 30 \text{ A}$; $-\text{di}_F/\text{dt} = 240 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}$; $T_{VJ} = 100^\circ\text{C}$	10	11	A

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle $d = 0.5$
Data according to IEC 60747

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Dim.	Millimeter		Inches	
	min	max	min	max
A	31.50	31.88	1.240	1.255
B	7.80	8.20	0.307	0.323
C	4.09	4.29	0.161	0.169
D	4.09	4.29	0.161	0.169
E	4.09	4.29	0.161	0.169
F	14.91	15.11	0.587	0.595
G	30.12	30.30	1.186	1.193
H	37.80	38.23	1.488	1.505
J	11.68	12.22	0.460	0.481
K	8.92	9.60	0.351	0.378
L	0.74	0.84	0.029	0.033
M	12.50	13.10	0.492	0.516
N	25.15	25.42	0.990	1.001
O	1.95	2.13	0.077	0.084
P	4.95	6.20	0.195	0.244
Q	26.54	26.90	1.045	1.059
R	3.94	4.42	0.155	0.167
S	4.55	4.85	0.179	0.191
T	24.59	25.25	0.968	0.994
U	-0.05	0.10	-0.002	0.004
V	3.20	5.50	0.126	0.217
W	19.81	21.08	0.780	0.830
Z	2.50	2.70	0.098	0.106

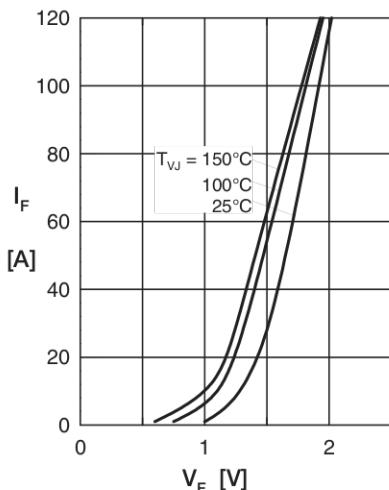


Fig. 1 Forward current vs. voltage drop

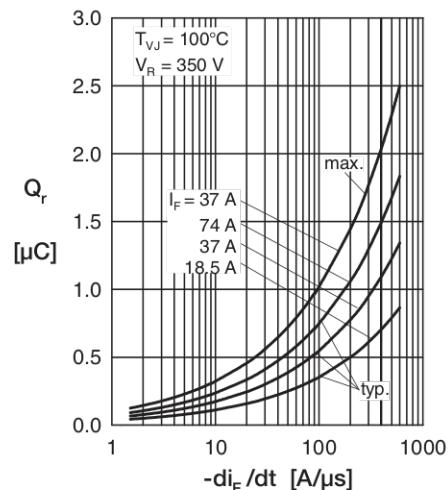
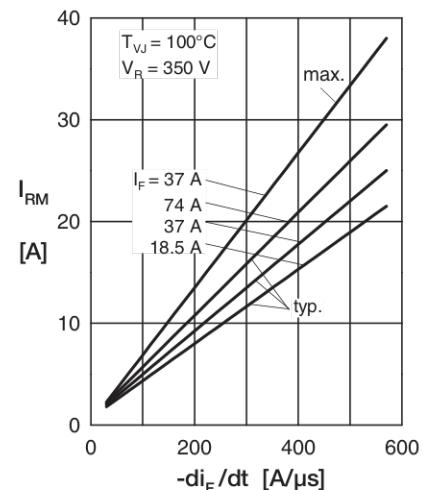
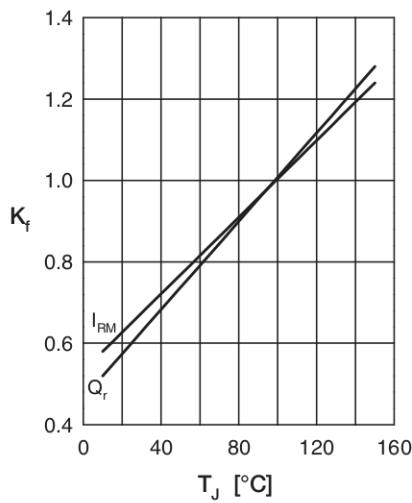
Fig. 2 Recovery charge versus $-di_F/dt$ Fig. 3 Peak reverse current versus $-di_F/dt$ 

Fig. 4 Dynamic parameters vs. junction temperature

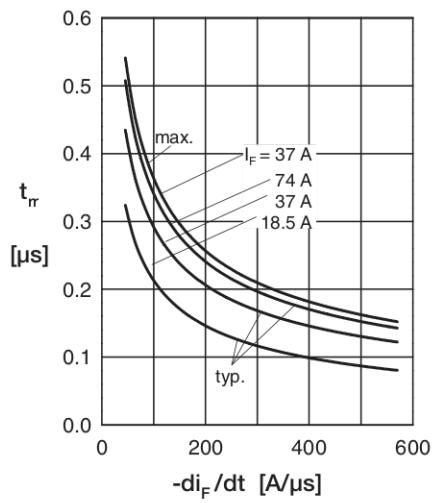
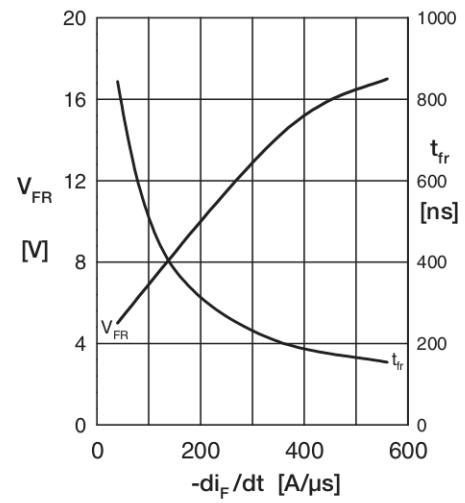
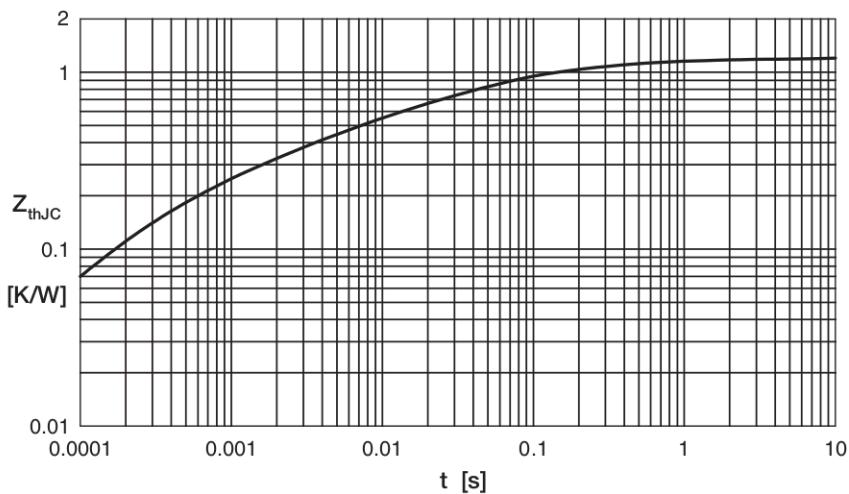
Fig. 5 Recovery time versus $-di_F/dt$ Fig. 6 Peak forward voltage versus $-di_F/dt$ 

Fig. 7 Transient thermal impedance junction to case